

ZXTN25040DFL

40V, SOT23, NPN low power transistor

Summary

$BV_{CEX} > 130V$

$BV_{CEO} > 40V$

$BV_{ECO} > 6V$

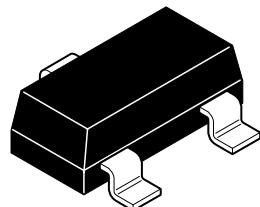
$I_{C(\text{cont})} = 1.5A$

$V_{CE(\text{sat})} < 85mV @ 1A$

$R_{CE(\text{sat})} = 59m\Omega$

$P_D = 350mW$

Complementary part number ZXTP25040DFL

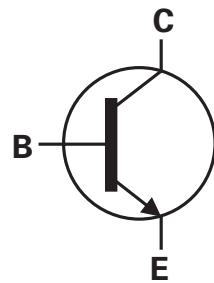


Description

Advanced process capability has been used to achieve high current gain hold up making this device ideal for applications requiring high pulse currents.

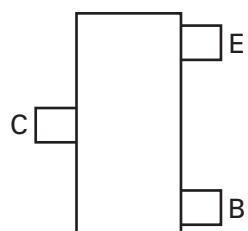
Features

- High peak current
- Low saturation voltage
- 130V forward blocking voltage
- 6V reverse blocking voltage



Applications

- MOSFET and IGBT gate driving
- DC-DC conversion
- LED driving
- Interface between low voltage IC's and loads



Pinout - top view

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25040DFLTA	7	8	3000

Device marking

1B7

ZXTN25040DFL

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V_{CBO}	130	V
Collector-emitter voltage (forward blocking)	V_{CEX}	130	V
Collector-emitter voltage	V_{CEO}	40	V
Emitter-collector voltage (reverse blocking)	V_{ECO}	6	V
Emitter-base voltage	V_{EBO}	7	V
Continuous collector current ^(a)	I_C	1.5	A
Base current	I_B	0.5	A
Peak pulse current	I_{CM}	6	A
Power dissipation at $T_{amb} = 25^\circ\text{C}$ ^(a)	P_D	350	mW
Linear derating factor		2.8	$\text{mW}/^\circ\text{C}$
Operating and storage temperature range	T_j, T_{stg}	-55 to 150	$^\circ\text{C}$

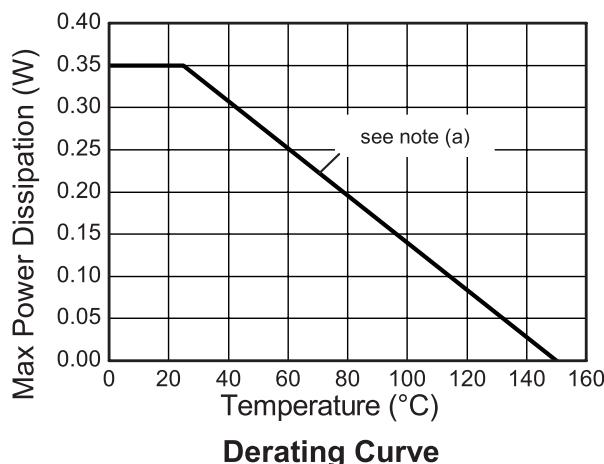
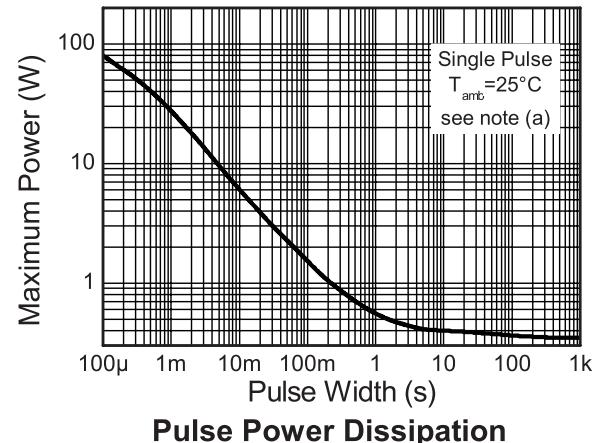
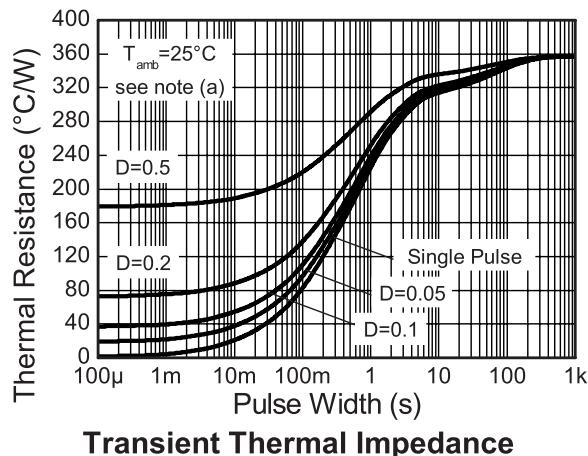
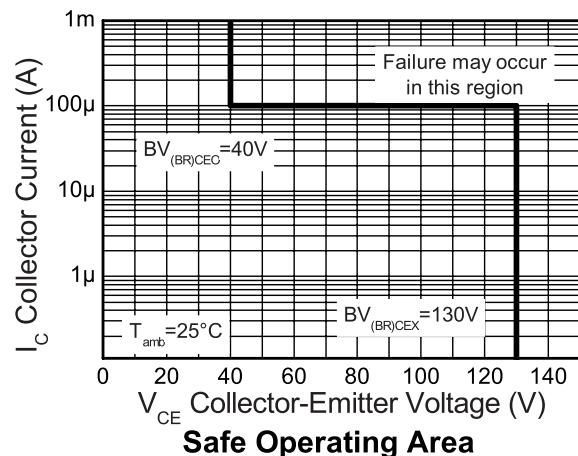
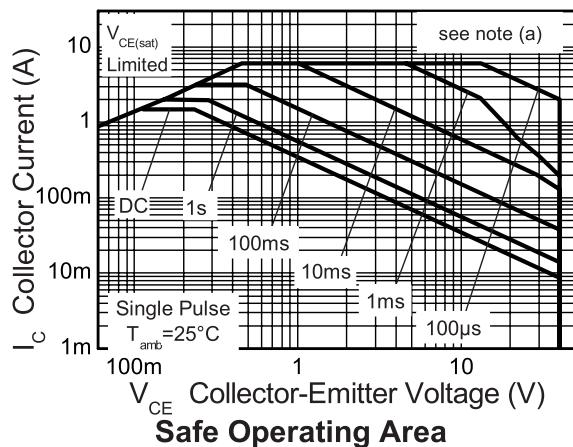
Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	357	$^\circ\text{C}/\text{W}$

NOTES:

(a) For a device surface mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics



ZXTN25040DFL

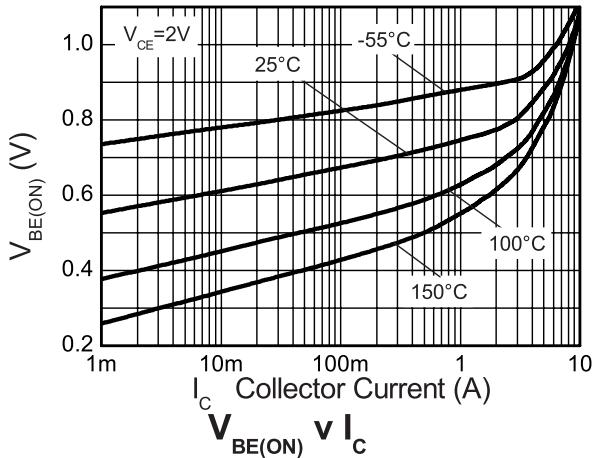
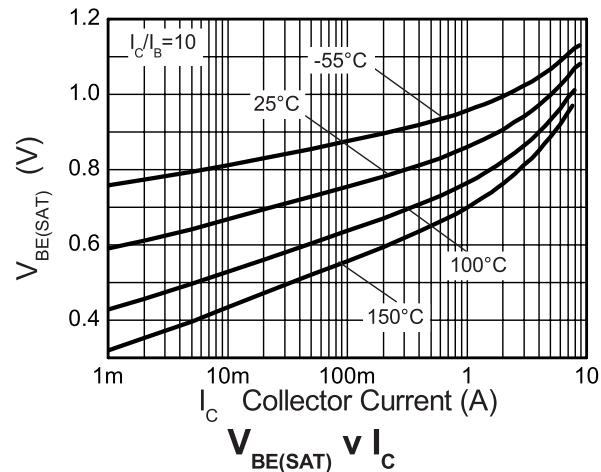
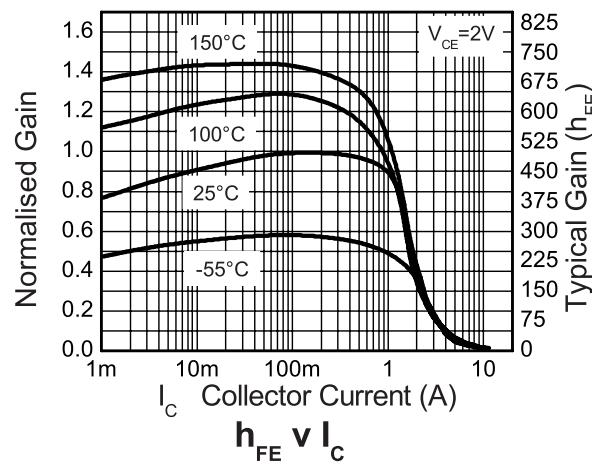
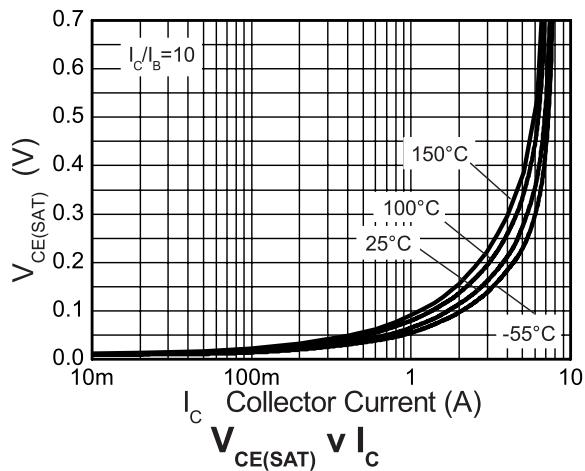
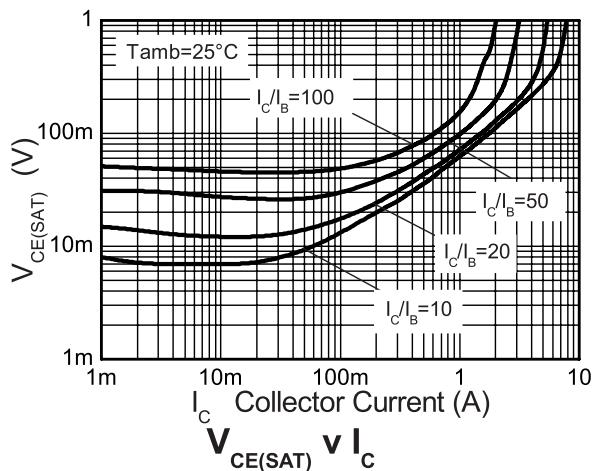
Electrical characteristics (at $T_{amb} = 25^\circ C$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	130	170		V	$I_C = 100\mu A$
Collector-emitter breakdown voltage (forward blocking)	BV_{CEX}	130	170		V	$I_C = 100\mu A; R_{BE} < 1k\Omega$ or $-1V < V_{BE} < 0.25V$
Collector-emitter breakdown voltage (base open)	BV_{CEO}	40	63		V	$I_C = 10mA$ (*)
Emitter-base breakdown voltage	BV_{EBO}	7	8.3		V	$I_E = 100\mu A$
Emitter-collector breakdown voltage (reverse blocking)	BV_{ECX}	6	7.4		V	$I_E = 100\mu A, R_{BC} < 1k\Omega$ or $0.25V > V_{BC} > -0.25V$
Emitter-collector breakdown voltage (base open)	BV_{ECO}	6	7.4		V	$I_E = 100\mu A,$
Collector cut-off current	I_{CBO}		<1	50 20	nA μA	$V_{CB} = 100V$ $V_{CB} = 100V, T_{amb} = 100^\circ C$
Collector emitter cut-off current	I_{CEX}		<1	100	nA	$V_{CE} = 100V; R_{BE} < 1k\Omega$ or $-1V < V_{BE} < 0.25V$
Emitter cut-off current	I_{EBO}		<1	50	nA	$V_{EB} = 5.6V$
Collector-emitter saturation voltage	$V_{CE(sat)}$		35 60 70 145 235	50 80 85 185 285	mV	$I_C = 0.5A, I_B = 50mA$ (*) $I_C = 0.5A, I_B = 10mA$ (*) $I_C = 1A, I_B = 100mA$ $I_C = 1.5A, I_B = 30mA$ (*) $I_C = 4A, I_B = 400mA$ (*)
Base-emitter saturation voltage	$V_{BE(sat)}$		840	950	mV	$I_C = 1.5A, I_B = 30mA$ (*)
Base-emitter turn-on voltage	$V_{BE(on)}$		770	850	mV	$I_C = 1.5A, V_{CE} = 2V$ (*)
Static forward current transfer ratio	h_{FE}	300 300 170 25	450 400 250 40	900		$I_C = 10mA, V_{CE} = 2V$ (*) $I_C = 1A, V_{CE} = 2V$ (*) $I_C = 1.5A, V_{CE} = 2V$ (*) $I_C = 4A, V_{CE} = 2V$ (*)
Transition frequency	f_T		190		MHz	$I_C = 50mA, V_{CE} = 10V$ $f = 100MHz$
Output capacitance	C_{obo}		11.7	20	pF	$V_{CB} = 10V, f = 1MHz$ (*)
Delay time	$t_{(d)}$		64		ns	$V_{CC} = 10V,$ $I_C = 1A,$ $I_{B1} = I_{B2} = 10mA.$
Rise time	$t_{(r)}$		108		ns	
Storage time	$t_{(s)}$		428		ns	
Fall time	$t_{(f)}$		130		ns	

NOTES:

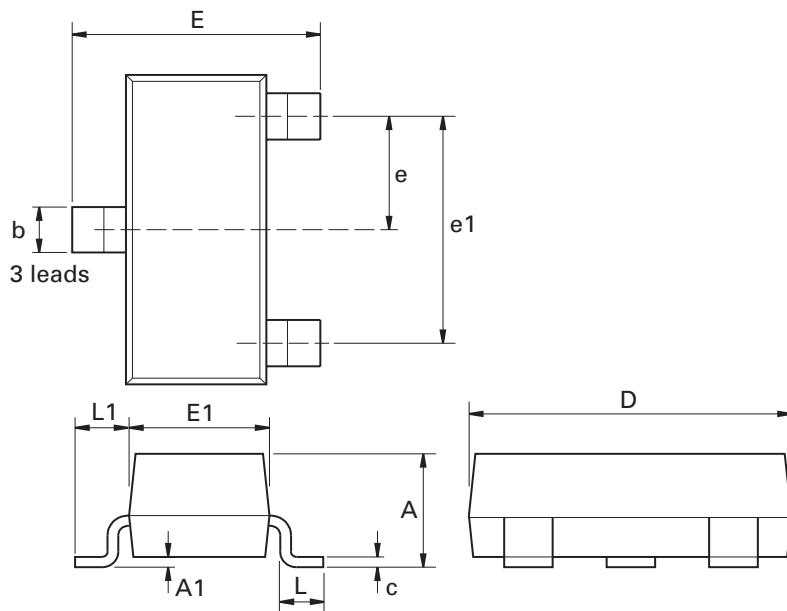
(*) Measured under pulsed conditions. Pulse width $\leq 300\mu s$; duty cycle $\leq 2\%$.

Typical characteristics



ZXTN25040DFL

Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	2.67	3.05	0.105	0.120	H	0.33	0.51	0.013	0.020
B	1.20	1.40	0.047	0.055	K	0.01	0.10	0.0004	0.004
C	-	1.10	-	0.043	L	2.10	2.50	0.083	0.0985
D	0.37	0.53	0.015	0.021	M	0.45	0.64	0.018	0.025
F	0.085	0.15	0.0034	0.0059	N	0.95 NOM		0.0375 NOM	
G	1.90 NOM		0.075 NOM		-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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